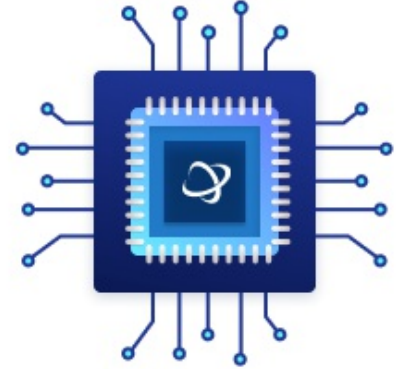


Power MOSFET; Package: D3 [S]; ID (A): 67; RDS(on) (Ohms): 0.038; BVDSS (V): 200;

Manufacturers	Microchip Technology, Inc
Package/Case	D3 [S]
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for APT20M38SVRG or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

Features

Eliminating Parasitic Oscillation between Parallel MOSFETs

High Frequency Resonant Half Bridge

Improved Power MOSFETS Boost Efficiency IN A 3.5kw Single Phase PFC

Introduction to MOSFETs

Latest Technology PT IGBTs vs. Power MOSFETs

Making Use of Gate Charge Information In MOSFET and IGBT Data Sheets

Optimizing MOSFET and IGBT Gate Current to Minimize dv/dt Induced Failures in SMPS Circuits

Turn Off Snubber Design for High Frequency Modules

VDS(on) VCE(sat) Measurement

Related Products



[APT5010JFLL](#)

Microchip Technology, Inc
SOT227



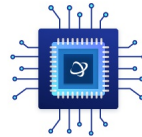
[APT5010LVRC](#)

Microchip Technology, Inc
TO264



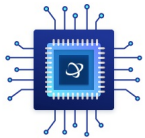
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Microchip Technology, Inc
97A/200V/MOS/1U



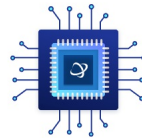
[APL602B2G](#)

Microchip Technology, Inc
T-MAX[B2



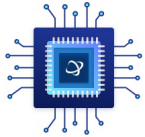
[APT6010JFLL](#)

Microchip Technology, Inc
APT



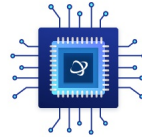
[APT6010B2FLLG](#)

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T-MAX[B2